

SCES765C - DECEMBER 2009 - REVISED JANUARY 2012

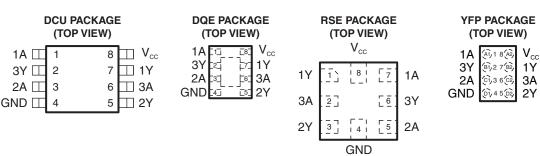
### LOW-POWER TRIPLE SCHMITT-TRIGGER BUFFER

Check for Samples: SN74AUP3G17

### **FEATURES**

- Available in the Texas Instruments NanoStar™ Package
- Low Static-Power Consumption (I<sub>CC</sub> = 0.9 µA Maximum)
- Low Dynamic-Power Consumption (C<sub>pd</sub> = 4.3 pF Typ at 3.3 V)
- Low Input Capacitance (C<sub>i</sub> = 1.5 pF Typical)
- Low Noise Overshoot and Undershoot <10% of V<sub>CC</sub>
- Ioff Supports Partial-Power-Down Mode
  Operation
- Wide Operating V<sub>CC</sub> Range of 0.8 V to 3.6 V

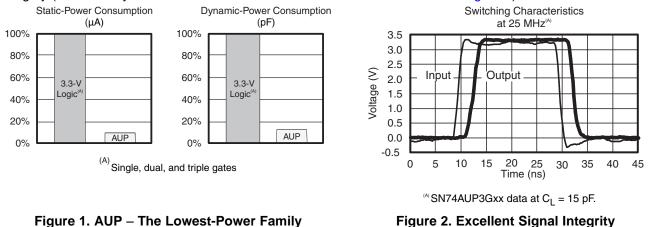
- Optimized for 3.3-V Operation
- 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- t<sub>pd</sub> = 5.1 ns Maximum at 3.3 V
- · Suitable for Point-to-Point Applications
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
  - 2000-V Human-Body Model (A114-B, Class II)
  - 1000-V Charged-Device Model (C101)

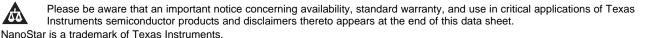


See mechanical drawings for dimensions.

### **DESCRIPTION/ORDERING INFORMATION**

The AUP family is TI's premier solution to the industry's low-power needs in battery-powered portable applications. This family ensures a very low static- and dynamic-power consumption across the entire  $V_{CC}$  range of 0.8 V to 3.6 V, resulting in increased battery life (see Figure 1). This product also maintains excellent signal integrity (see the very low undershoot and overshoot characteristics shown in Figure 2).







SCES765C-DECEMBER 2009-REVISED JANUARY 2012

The SN74LVC3G17 contains three buffers and performs the Boolean function Y = A. The device functions as three independent buffers but, because of Schmitt action, it may have different input threshold levels for positive-going ( $V_{T+}$ ) and negative-going ( $V_{T-}$ ) signals.

NanoStar<sup>™</sup> package technology is a major breakthrough in IC packaging concepts, using the die as the package.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### ORDERING INFORMATION<sup>(1)</sup>

T <sub>A</sub>	PACKAGE <sup>(2)</sup>		ORDERABLE PART NUMBER	TOP-SIDE MARKING <sup>(3)</sup>
	NanoStar™ – WCSP (DSBGA) 0.23-mm Large Bump – YFP (Pb-free)	Reel of 3000	SN74AUP3G17YFPR	H7_
–40°C to 85°C	uQFN – DQE	Reel of 5000	SN74AUP3G17DQER	TY
	QFN – RSE	Reel of 5000	SN74AUP3G17RSER	TY
	SSOP – DCU	Reel of 3000	SN74AUP3G17DCUR	H17_

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

(2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

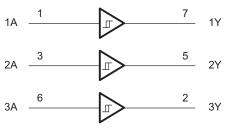
(3) DCU: The actual top-side marking has one additional character that designates the wafer fab/assembly site.

YFP: The actual top-side marking has three preceding characters to denote year, month, and sequence code, and one following character to designate the wafer fab/assembly site. Pin 1 identifier indicates solder-bump composition (1 = SnPb, • = Pb-free).

#### FUNCTION TABLE

INPUT A	OUTPUT Y
Н	Н
L	L

#### LOGIC DIAGRAM (POSITIVE LOGIC)



Pin numbers shown are for the DCU and DQE packages.



SCES765C - DECEMBER 2009-REVISED JANUARY 2012

www.ti.com

#### **ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>**

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage range		-0.5	4.6	V	
VI	Input voltage range <sup>(2)</sup>		-0.5	4.6	V	
Vo	Voltage range applied to any output in the I	nigh-impedance or power-off state <sup>(2)</sup>	-0.5	4.6	V	
Vo	Output voltage range in the high or low stat	e <sup>(2)</sup>	-0.5	V <sub>CC</sub> + 0.5	V	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA	
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA	
I <sub>O</sub>	Continuous output current			±20	mA	
	Continuous current through $V_{CC}$ or GND			±50	mA	
		DCU package		220		
0	Declares the resulting a damag (3)	DQE package		261	°C/W	
$\theta_{JA}$	Package thermal impedance <sup>(3)</sup>	RSE package		253	0/11	
		YFP package		132		
T <sub>stg</sub>	Storage temperature range		-65	150	°C	

Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating (1) conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed. The package thermal impedance is calculated in accordance with JESD 51-7. (2) (3)

SCES765C - DECEMBER 2009 - REVISED JANUARY 2012

NSTRUMENTS

ÈXAS

### **RECOMMENDED OPERATING CONDITIONS (1)**

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage		0.8	3.6	V
VI	Input voltage		0	3.6	V
Vo	Output voltage		0	V <sub>CC</sub>	V
		$V_{CC} = 0.8 V$		-20	μA
		V <sub>CC</sub> = 1.1 V		-1.1	
	Link laural autout autout	$V_{CC} = 1.4 V$		-1.7	–1.9 mA
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 1.65		-1.9	
		V <sub>CC</sub> = 2.3 V		-3.1	
		$V_{CC} = 3 V$		-4	
		V <sub>CC</sub> = 0.8 V		20	μA
		V <sub>CC</sub> = 1.1 V		1.1	
	Level be all a days for some of	$V_{CC} = 1.4 V$		1.7	
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 1.65 V		1.9	mA
		V <sub>CC</sub> = 2.3 V		3.1	
		V <sub>CC</sub> = 3 V		4	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C

(1) All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



SCES765C - DECEMBER 2009-REVISED JANUARY 2012

www.ti.com

#### ELECTRICAL CHARACTERISTICS

over recommended operating free-air temperature range (unless otherwise noted)

	TEST CONDITIONS	V	T <sub>A</sub>	= 25°C	T <sub>A</sub> = -40°C	to 85°C	
PARAMETER	TEST CONDITIONS	V <sub>CC</sub>	MIN	TYP MAX	MIN	MAX	UNIT
		0.8 V	0.3	0.6	0.3	0.6	
/ <sub>T+</sub>		1.1 V	0.53	0.9	0.53	0.9	
Positive-going		1.4 V	0.74	1.11	0.74	1.11	V
nput threshold		1.65 V	0.91	1.29	0.91	1.29	v
voltage		2.3 V	1.37	1.77	1.37	1.77	
		3 V	1.88	2.29	1.88	2.29	
		0.8 V	0.1	0.6	0.1	0.6	
V <sub>T-</sub>		1.1 V	0.26	0.65	0.26	0.65	
Negative-going		1.4 V	0.39	0.75	0.39	0.75	V
input threshold		1.65 V	0.47	0.84	0.47	0.84	
voltage		2.3 V	0.69	1.04	0.69	1.04	
		3 V	0.88	1.24	0.88	1.24	
		0.8 V	0.07	0.5	0.07	0.5	
		1.1 V	0.08	0.46	0.08	0.46	
ΔV <sub>T</sub>		1.4 V	0.18	0.56	0.18	0.56	V
Hysteresis (V <sub>T+</sub> – V <sub>T–</sub> )		1.65 V	0.27	0.66	0.27	0.66	
		2.3 V	0.53	0.92	0.53	0.92	
		3 V	0.79	1.31	0.79	1.31	
	I <sub>OH</sub> = -20 μA	0.8 V to 3.6 V	V <sub>CC</sub> – 0.1		V <sub>CC</sub> – 0.1		
	I <sub>OH</sub> = -1.1 mA	1.1 V	0.75 × V <sub>CC</sub>		0.7 × V <sub>CC</sub>		
	I <sub>OH</sub> = -1.7 mA	1.4 V	1.11		1.03		
	I <sub>OH</sub> = -1.9 mA	1.65 V	1.32		1.3		
V <sub>OH</sub>	I <sub>OH</sub> = -2.3 mA	0.01/	2.05		1.97		V
	I <sub>OH</sub> = -3.1 mA	2.3 V	1.9		1.85		
	I <sub>OH</sub> = -2.7 mA	0.1/	2.72		2.67		
	$I_{OH} = -4 \text{ mA}$	3 V	2.6		2.55		
	I <sub>OL</sub> = 20 μA	0.8 V to 3.6 V		0.1		0.1	
	I <sub>OL</sub> = 1.1 mA	1.1 V		$0.3 \times V_{CC}$		$0.3 \times V_{CC}$	
	I <sub>OL</sub> = 1.7 mA	1.4 V		0.31		0.37	
N/	I <sub>OL</sub> = 1.9 mA	1.65 V		0.31		0.35	
V <sub>OL</sub>	I <sub>OL</sub> = 2.3 mA	0.01/		0.31		0.33	V
	I <sub>OL</sub> = 3.1 mA	2.3 V		0.44		0.45	
	I <sub>OL</sub> = 2.7 mA	0.14		0.31		0.33	
	$I_{OL} = 4 \text{ mA}$	3 V		0.44		0.45	
II A or B input	$V_I = GND$ to 3.6 V	0 V to 3.6 V		0.1		0.5	μA
l <sub>off</sub>	$V_{I}$ or $V_{O} = 0$ V to 3.6 V	0 V		0.2		0.6	μA
Δl <sub>off</sub>	$V_{I}$ or $V_{O}$ = 0 V to 3.6 V	0 V to 0.2 V		0.2		0.6	μA
lcc	$V_{I} = GND \text{ or}$ $(V_{CC} \text{ to } 3.6 \text{ V}),$ $I_{O} = 0$	0.8 V to 3.6 V		0.5		0.9	μA
ΔI <sub>CC</sub>	$V_1 = V_{CC} - 0.6 V^{(1)},$ $I_0 = 0$	3.3 V		40		50	μA
C <sub>i</sub>	$V_{I} = V_{CC}$ or GND	0 V 3.6 V		1.5			pF
	V <sub>O</sub> = GND			1.5			

(1) One input at  $V_{CC}$  – 0.6 V, other input at  $V_{CC}$  or GND

SCES765C - DECEMBER 2009 - REVISED JANUARY 2012

#### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 5 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	T <sub>A</sub>	= 25°C		$T_A = -40^{\circ}C$	to 85°C	
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	M IN	MAX	UNIT
			0.8 V		22.7				
		_	1.2 V ± 0.1 V	6.3	8	12.8	3.9	14.6	
	•	v	1.5 V ± 0.1 V	4.6	5.8	8.4	2.8	10	~~~
t <sub>pd</sub>	A	r	1.8 V ± 0.15 V	3.9	4.8	7.2	2.4	8.1	ns
			2.5 V ± 0.2 V	3.1	3.6	5.1	2	6.1	
			3.3 V ± 0.3 V	2.7	3	4.4	1.9	5.1	

### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range, C<sub>L</sub> = 10 pF (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	М	TA	= 25°C		$T_A = -40^{\circ}C$	to 85°C	UNIT			
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT			
			0.8 V		25.1							
			1.2 V ± 0.1 V	7.1	9.1	13.8	4.7	15.6				
	^	V	V	V	Y	1.5 V ± 0.1 V	5.2	6.5	9.4	3.4	11	20
t <sub>pd</sub>	A	Т	1.8 V ± 0.15 V	4.5	5.4	8	2.9	9	ns			
		1	2.5 V ± 0.2 V	3.5	4.2	5.7	2.4	6.8				
			3.3 V ± 0.3 V	3.1	3.5	4.9	2.2	5.7				

### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 15 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

DADAMETER	FROM	то	М	TA	= 25°C		$T_A = -40^{\circ}C t$	o 85°C	UNIT		
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT		
			0.8 V		27.6						
			1.2 V ± 0.1 V	7.8	10.1	14.8	5.3	16.7			
+	А	V	V	Y	1.5 V ± 0.1 V	5.8	7.4	10.3	3.9	12	20
t <sub>pd</sub>	A	r	1.8 V ± 0.15 V	5	6.1	8.8	3.4	10	ns		
				2.5 V ± 0.2 V	4	4.7	6.4	2.8	7.5		
			3.3 V ± 0.3 V	3.5	4.1	5.4	2.6	6.2			

### SWITCHING CHARACTERISTICS

over recommended operating free-air temperature range,  $C_L = 30 \text{ pF}$  (unless otherwise noted) (see Figure 3 and Figure 4)

PARAMETER	FROM	то	V	Τ,	∖ = 25°C	;	T <sub>A</sub> = −40°C t	o 85°C	UNIT
PARAMETER	(INPUT)	(OUTPUT)	V <sub>cc</sub>	MIN	TYP	MAX	MIN	MAX	UNIT
			0.8 V		35.1				
			1.2 V ± 0.1 V	10	13.1	18.1	7.5	19.8	
+	А	v	1.5 V ± 0.1 V	7.4	9.6	12.9	5.6	14.9	
t <sub>pd</sub>	A	T	1.8 V ± 0.15 V	6.4	7.9	11	4.8	12.4	ns
			2.5 V ± 0.2 V	5.2	6.1	8.1	4	9.3	
			3.3 V ± 0.3 V	4.6	5.3	6.9	3.6	7.7	



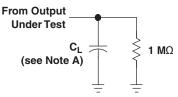
#### SCES765C - DECEMBER 2009-REVISED JANUARY 2012

### **OPERATING CHARACTERISTICS**

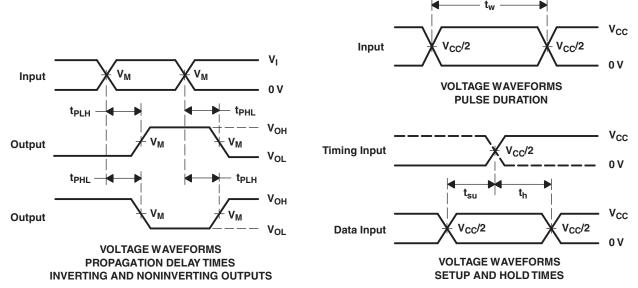
	PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	TYP	UNIT
			0.8 V	4	
			1.2 V ± 0.1 V	4	
~	Device discipation constitution		1.5 V ± 0.1 V	4	
C <sub>pd</sub>	Power dissipation capacitance	f = 10 MHz	1.8 V ± 0.15 V	4	pF
			2.5 V ± 0.2 V	4.1	
			3.3 V ± 0.3 V	4.3	

SCES765C - DECEMBER 2009-REVISED JANUARY 2012

#### PARAMETER MEASUREMENT INFORMATION (Propagation Delays, Setup and Hold Times, and Pulse Width)



	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	$V_{CC} = 1.5 \text{ V}$ $\pm 0.1 \text{ V}$	V <sub>CC</sub> = 1.8 V ± 0.15 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V	$\begin{array}{c} V_{CC} = 3.3 \ V \\ \pm \ 0.3 \ V \end{array}$
CL	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
VI	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>



- A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_0 = 50 \Omega$ , for propagation delays  $t_r/t_f = 3$  ns, for setup and hold times and pulse width  $t_r/t_f = 1.2$  ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- F. All parameters and waveforms are not applicable to all devices.

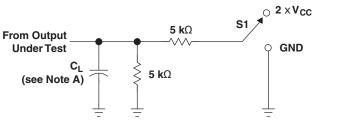
Figure 3. Load Circuit and Voltage Waveforms

LOAD CIRCUIT

8



#### PARAMETER MEASUREMENT INFORMATION (Enable and Disable Times)

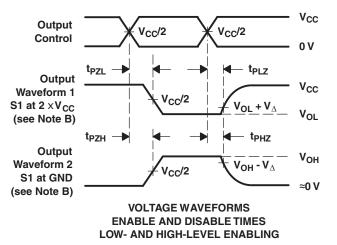


TEST	S1
t <sub>PLZ</sub> /t <sub>PZL</sub>	2 × V <sub>CC</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

SCES765C - DECEMBER 2009-REVISED JANUARY 2012

LOAD CIRCUIT

	V <sub>CC</sub> = 0.8 V	V <sub>CC</sub> = 1.2 V ± 0.1 V	V <sub>CC</sub> = 1.5 V ± 0.1 V	$V_{CC}$ = 1.8 V ± 0.15 V	$V_{CC}$ = 2.5 V $\pm$ 0.2 V	$V_{CC}$ = 3.3 V $\pm$ 0.3 V
С <sub>L</sub>	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF	5, 10, 15, 30 pF
V <sub>M</sub>	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2	V <sub>CC</sub> /2
V <sub>I</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>	V <sub>CC</sub>
V <sub>Δ</sub>	0.1 V	0.1 V	0.1 V	0.15 V	0.15 V	0.3 V



- A. C<sub>L</sub> includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>0</sub> = 50  $\Omega$ , t<sub>r</sub>/t<sub>f</sub> = 3 ns.
- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- G. All parameters and waveforms are not applicable to all devices.

Figure 4. Load Circuit and Voltage Waveforms

SCES765C-DECEMBER 2009-REVISED JANUARY 2012

### **REVISION HISTORY**

Cł	nanges from Revision B (July 2010) to Revision C	Page
•	Changed logic diagram from inverting to non-inverting amplifiers	2
•	Deleted input transition rise or fall rate ( $\Delta t/\Delta v$ ) paramater from Recommended Operation Conditons table	4

Copyright © 2009–2012, Texas Instruments Incorporated



www.ti.com



### **PACKAGING INFORMATION**

Orderable part number	Status	Material type	Package   Pins	Package qty   Carrier	RoHS	Lead finish/	MSL rating/	Op temp (°C)	Part marking
	(1)	(2)			(3)	Ball material	Peak reflow		(6)
						(4)	(5)		
SN74AUP3G17DCUR	Active	Production	VSSOP (DCU)   8	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H17R
SN74AUP3G17DCUR.B	Active	Production	VSSOP (DCU)   8	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H17R
SN74AUP3G17DCURG4	Active	Production	VSSOP (DCU)   8	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H17R
SN74AUP3G17DCURG4.B	Active	Production	VSSOP (DCU)   8	3000   LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	H17R
SN74AUP3G17DQER	Active	Production	X2SON (DQE)   8	5000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	TY
SN74AUP3G17DQER.B	Active	Production	X2SON (DQE)   8	5000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	TY
SN74AUP3G17RSER	Active	Production	UQFN (RSE)   8	5000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	TY
SN74AUP3G17RSER.B	Active	Production	UQFN (RSE)   8	5000   LARGE T&R	Yes	NIPDAUAG	Level-1-260C-UNLIM	-40 to 85	TY
SN74AUP3G17YFPR	Active	Production	DSBGA (YFP)   8	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	H7N
SN74AUP3G17YFPR.B	Active	Production	DSBGA (YFP)   8	3000   LARGE T&R	Yes	SNAGCU	Level-1-260C-UNLIM	-40 to 85	H7N

<sup>(1)</sup> **Status:** For more details on status, see our product life cycle.

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative



### PACKAGE OPTION ADDENDUM

17-Jun-2025

and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

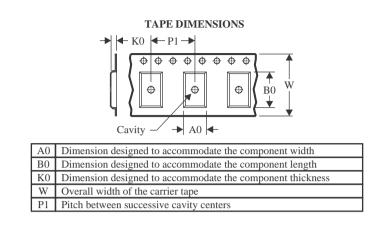


Texas

STRUMENTS

### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP3G17DCUR	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AUP3G17DCURG4	VSSOP	DCU	8	3000	180.0	8.4	2.25	3.35	1.05	4.0	8.0	Q3
SN74AUP3G17DQER	X2SON	DQE	8	5000	180.0	8.4	1.2	1.6	0.55	4.0	8.0	Q1
SN74AUP3G17RSER	UQFN	RSE	8	5000	180.0	8.4	1.7	1.7	0.7	4.0	8.0	Q2
SN74AUP3G17YFPR	DSBGA	YFP	8	3000	178.0	9.2	0.9	1.75	0.6	4.0	8.0	Q1



## PACKAGE MATERIALS INFORMATION

18-Jun-2025



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AUP3G17DCUR	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74AUP3G17DCURG4	VSSOP	DCU	8	3000	202.0	201.0	28.0
SN74AUP3G17DQER	X2SON	DQE	8	5000	202.0	201.0	28.0
SN74AUP3G17RSER	UQFN	RSE	8	5000	202.0	201.0	28.0
SN74AUP3G17YFPR	DSBGA	YFP	8	3000	220.0	220.0	35.0

# **DCU0008A**



# **PACKAGE OUTLINE**

### VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side. 4. Reference JEDEC registration MO-187 variation CA.



# DCU0008A

# **EXAMPLE BOARD LAYOUT**

### VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

5. Publication IPC-7351 may have alternate designs.

6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



## DCU0008A

# **EXAMPLE STENCIL DESIGN**

### VSSOP - 0.9 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

8. Board assembly site may have different recommendations for stencil design.



<sup>7.</sup> Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

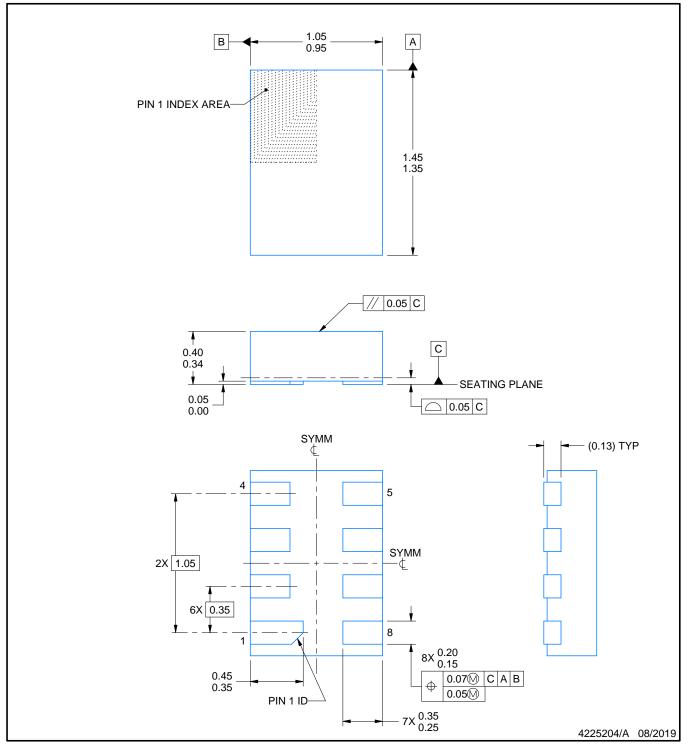
# **DQE0008A**



## **PACKAGE OUTLINE**

### X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
   This drawing is subject to change without notice.
   This package complies to JEDEC MO-287 variation X2EAF.

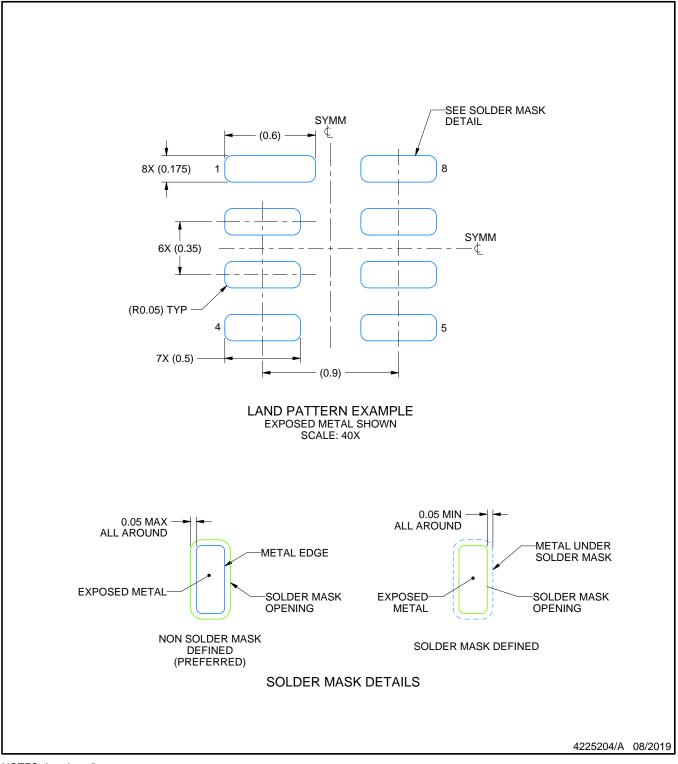


## **DQE0008A**

# **EXAMPLE BOARD LAYOUT**

### X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

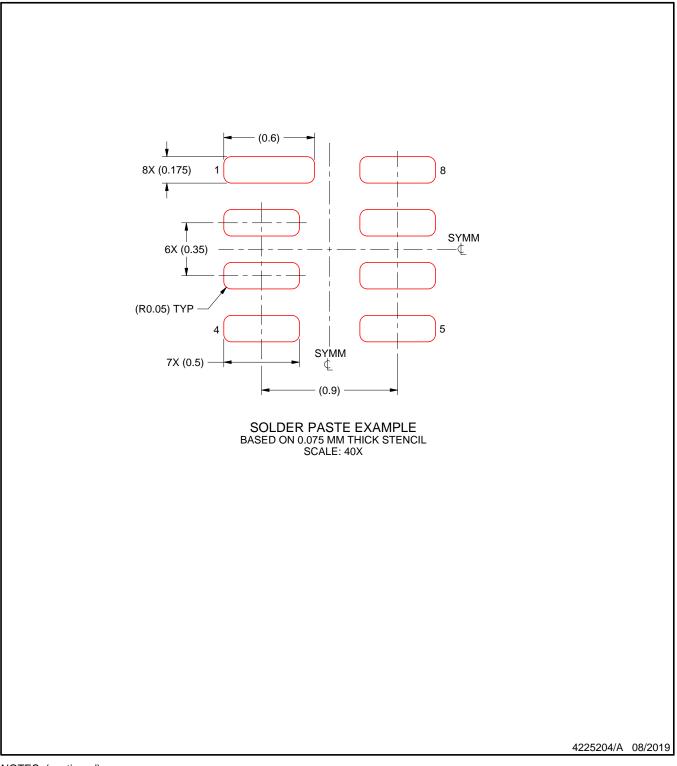


# **DQE0008A**

# **EXAMPLE STENCIL DESIGN**

### X2SON - 0.4 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



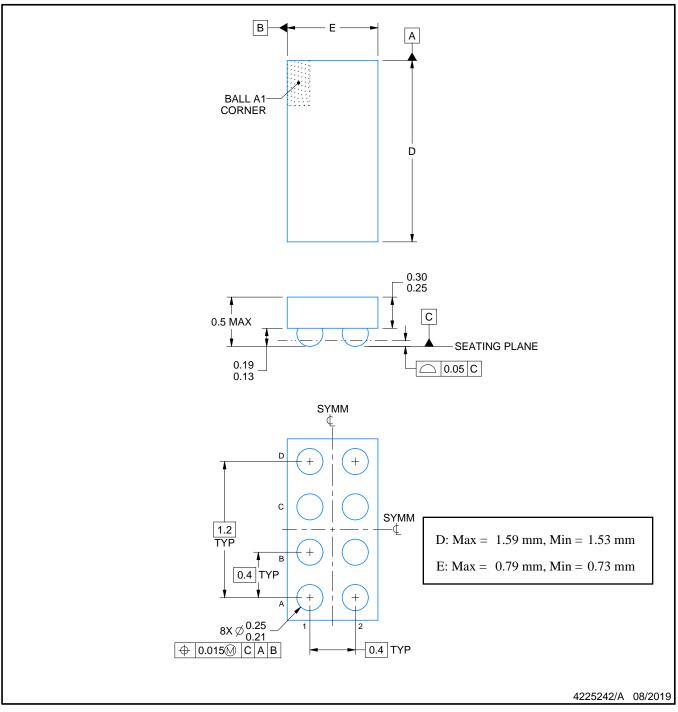
# **YFP0008**



## **PACKAGE OUTLINE**

### DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice.

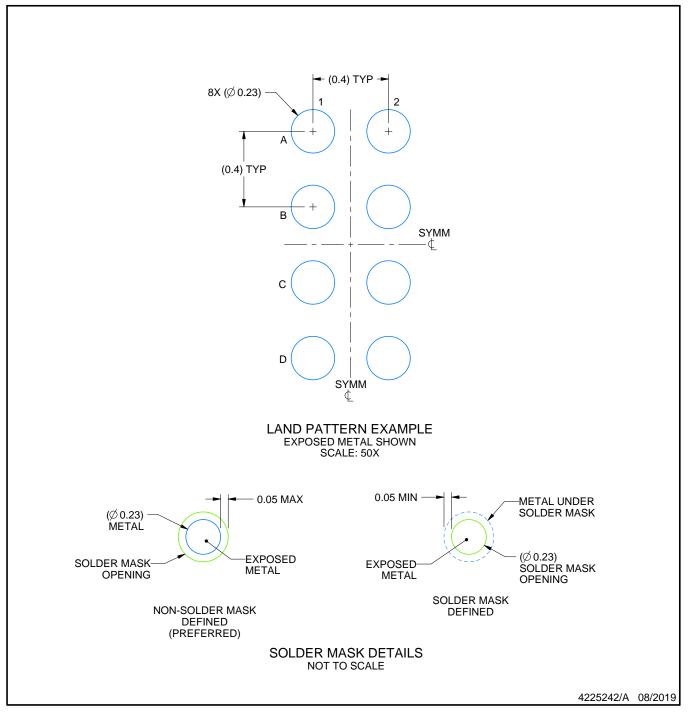


# YFP0008

# **EXAMPLE BOARD LAYOUT**

### DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

 Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. See Texas Instruments Literature No. SNVA009 (www.ti.com/lit/snva009).

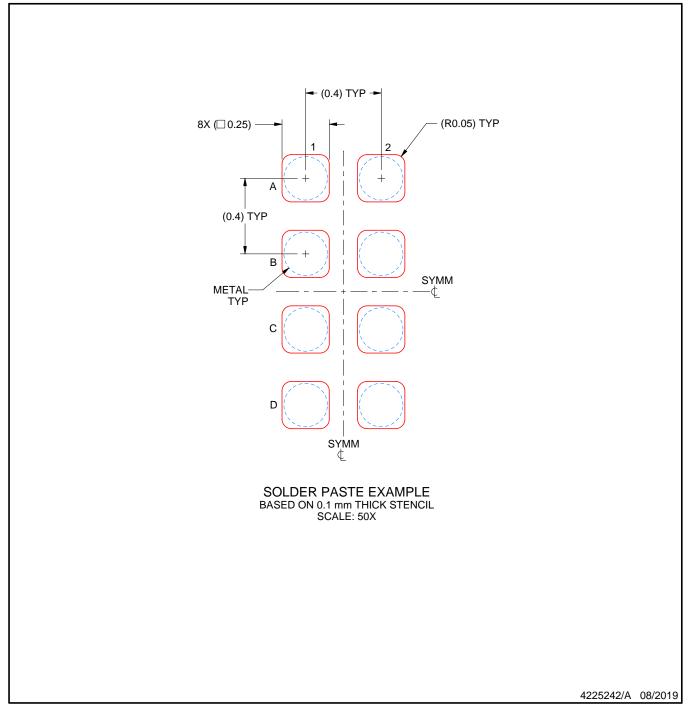


# YFP0008

# **EXAMPLE STENCIL DESIGN**

### DSBGA - 0.5 mm max height

DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



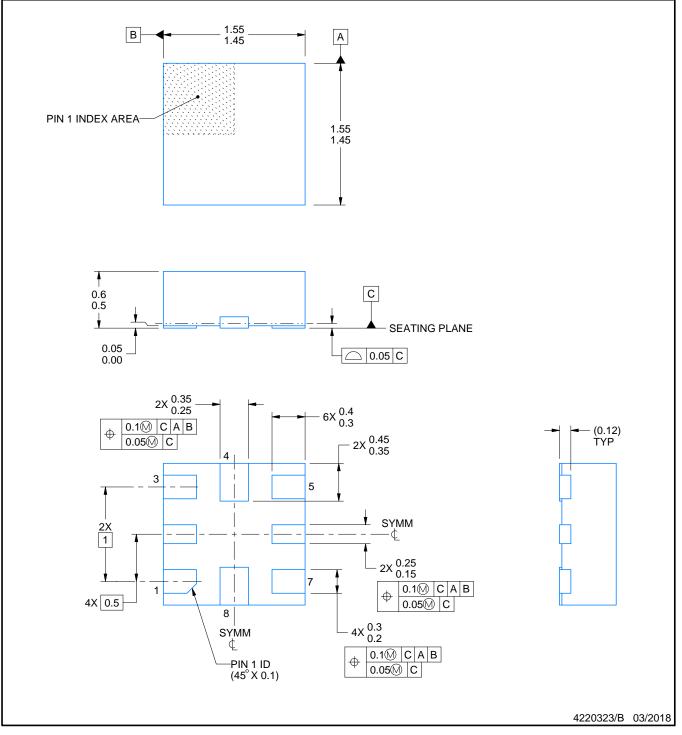
# **RSE0008A**



# **PACKAGE OUTLINE**

### UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.

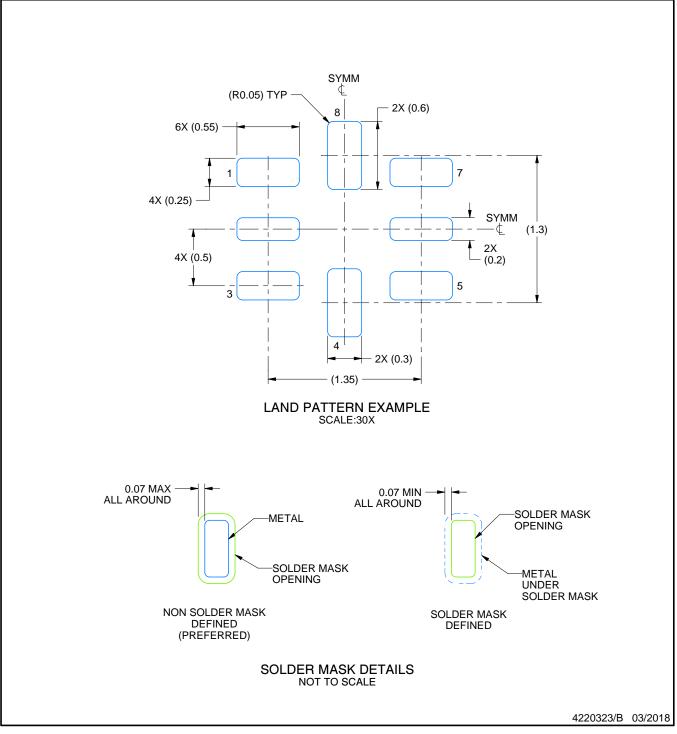


# **RSE0008A**

# **EXAMPLE BOARD LAYOUT**

### UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

3. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).

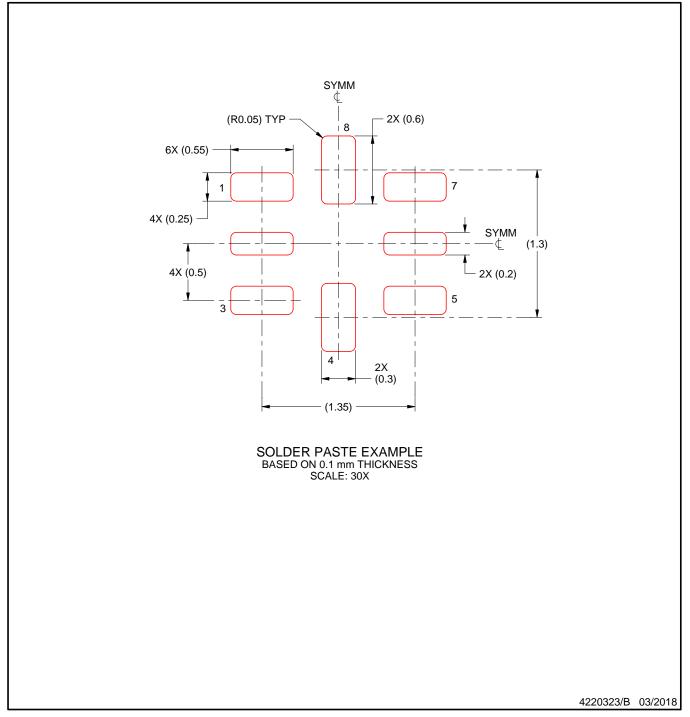


## **RSE0008A**

# **EXAMPLE STENCIL DESIGN**

### UQFN - 0.6 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2025, Texas Instruments Incorporated